

Inverting Octal 3-STATE Buffer, Octal 3-STATE Buffer

MM74HC540, MM74HC541

General Description

The MM74HC540 and MM74HC541 3-STATE buffers utilize advanced silicon-gate CMOS technology. They possess high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits achieve speeds comparable to low power Schottky devices, while retaining the advantage of CMOS circuitry, i.e., high noise immunity, and low power consumption. Both devices have a fanout of 15 LS-TTL equivalent inputs.

The MM74HC540 is an inverting buffer and the MM74HC541 is a non-inverting buffer. The 3-STATE control gate operates as a two-input NOR such that if either $\overline{G1}$ or $\overline{G2}$ are HIGH, all eight outputs are in the high-impedance state.

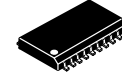
In order to enhance PC board layout, the MM74HC540 and MM74HC541 offers a pinout having inputs and outputs on opposite sides of the package. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- Typical Propagation Delay: 12 ns
- 3-STATE Outputs for Connection to System Buses
- Wide Power Supply Range: 2-6 V
- Low Quiescent Current: 160 μ A Maximum (74HC Series)
- Output Current: 6 mA
- These are Pb-Free Devices



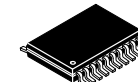
SOIC-20 WB
CASE 751D-05



SOIC-20, 300 mils
CASE 751BJ-01

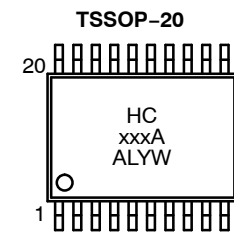
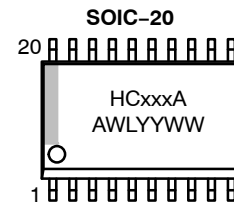


TSSOP-20 WB
CASE 948E



TSSOP-20, 4.4x6.5
CASE 948AQ-01

MARKING DIAGRAMS

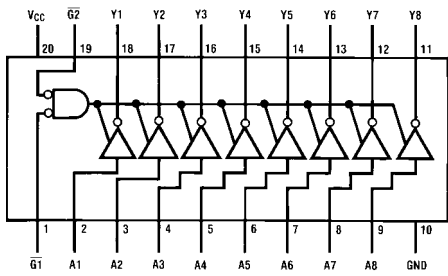


HCxxxA = Specific Device Code
 xxx = 540, 541
 A = Assembly Location
 WL, L = Wafer Lot Number
 Y = Year
 WW, YW = Work Week

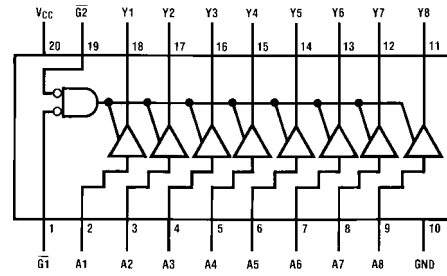
ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

MM74HC540, MM74HC541



MM74HC540 (Top View)



MM74HC541 (Top View)

Figure 1. Connection Diagrams
(Pin Assignments for SOIC and TSSOP)

ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol	Rating	Value	Unit	
V_{CC}	Supply Voltage	-0.5 to +7.0 V	V	
V_{IN}	DC Input Voltage	-0.5 to $V_{CC} + 0.5$ V	V	
V_{OUT}	DC Output Voltage	-0.5 to $V_{CC} + 0.5$ V	V	
I_{CD}	Clamp Diode Current	±20	mA	
I_{OUT}	DC Output Current, per pin	±35	mA	
I_{CC}	DC V_{CC} or GND Current, per pin	±70	mA	
T_{STG}	Storage Temperature Range	-65 to +150	°C	
P_D	Power Dissipation	Note 2	600	mW
		S. O. Package only	500	mW
T_L	Lead Temperature (Soldering 10 seconds)	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Unless otherwise specified all voltages are referenced to ground.
2. Power dissipation temperature derating – plastic "N" package: 12 mW/°C from 65°C to 85°C.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V_{CC}	Supply Voltage	2	6	V	
V_{IN}, V_{OUT}	DC Input or Output Voltage	0	V_{CC}	V	
T_A	Operating Temperature Range	-55	+125	°C	
t_r, t_f	Input Rise or Fall Times	$V_{CC} = 2.0$ V	-	1000	ns
		$V_{CC} = 4.5$ V	-	500	ns
		$V_{CC} = 6.0$ V	-	400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

MM74HC540, MM74HC541

DC ELECTRICAL CHARACTERISTICS (Note 3)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		T _A = -40 to 85°C	T _A = -55 to 125°C	Unit
				Typ	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage		2.0 V		1.5	1.5	1.5	V
			4.5 V		3.15	3.15	3.15	V
			6.0 V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Level Input Voltage		2.0 V		0.5	0.5	0.5	V
			4.5 V		1.35	1.35	1.35	V
			6.0 V		1.8	1.8	1.8	V
V _{OH}	Minimum HIGH Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0 V	2.0	1.9	1.9	1.9	V
			4.5 V	4.5	4.4	4.4	4.4	V
			6.0 V	6.0	5.9	5.9	5.9	V
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 6.0 mA I _{OUT} ≤ 7.8 mA	4.5 V	4.2	3.98	3.84	3.7	V
			6.0 V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0 V	0	0.1	0.1	0.1	V
			4.5 V	0	0.1	0.1	0.1	V
			6.0 V	0	0.1	0.1	0.1	V
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 6.0 mA I _{OUT} ≤ 7.8 mA	4.5 V	0.2	0.26	0.33	0.4	V
			6.0 V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input Current	V _{IN} = V _{CC} or GND	6.0 V		±0.1	±1.0	±1.0	μA
I _{OZ}	Maximum 3-STATE Output Leakage Current	V _{IN} = V _{IH} or V _{IL} , G̅ = V _{IH} V _{OUT} = V _{CC} or GND	6.0 V		±0.5	±5	±10	μA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND I _{OUT} = 0 μA	6.0 V		8.0	80	160	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. For a power supply of 5 V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V respectively. (The V_{IH} value at 5.5 V is 3.85 V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0 V values should be used.

AC ELECTRICAL CHARACTERISTICS

(V_{CC} = 5 V, T_A = 25°C, t_r = t_f = 6 ns)

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Unit
t _{PHL} , t _{PLH}	Maximum Propagation Delay (540)	C _L = 45 pF	12	18	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay (541)	C _L = 45 pF	14	20	ns
t _{PZH} , t _{PZL}	Maximum Output Enable Time	R _L = 1 kΩ C _L = 45 pF	17	28	ns
t _{PHZ} , t _{PLZ}	Maximum Output Disable Time	R _L = 1 kΩ C _L = 5 pF	15	25	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MM74HC540, MM74HC541

AC ELECTRICAL CHARACTERISTICS

($V_{CC} = 2.0\text{ V to }6.0\text{ V}$, $C_L = 50\text{ pF}$, $t_r = t_f = 6\text{ ns}$, unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25^\circ\text{C}$		$T_A = -40\text{ to }85^\circ\text{C}$	$T_A = -55\text{ to }125^\circ\text{C}$	Unit
				Typ	Guaranteed Limits			
t_{PHL} , t_{PLH}	Maximum Propagation Delay (540)	$C_L = 50\text{ pF}$	2.0 V	55	100	126	149	ns
		$C_L = 150\text{ pF}$	2.0 V	83	150	190	224	ns
		$C_L = 50\text{ pF}$	4.5 V	12	20	25	30	ns
		$C_L = 150\text{ pF}$	4.5 V	22	30	38	45	ns
t_{PHL} , t_{PLH}	Maximum Propagation Delay (541)	$C_L = 50\text{ pF}$	2.0 V	58	115	145	171	ns
		$C_L = 150\text{ pF}$	2.0 V	83	165	208	246	ns
		$C_L = 50\text{ pF}$	4.5 V	14	23	29	34	ns
		$C_L = 150\text{ pF}$	4.5 V	17	33	42	49	ns
t_{PZH} , t_{PZL}	Maximum Output Enable Time	$R_L = 1\text{ k}\Omega$	2.0 V	75	150	189	224	ns
		$C_L = 50\text{ pF}$	4.5 V	100	200	252	298	ns
		$C_L = 150\text{ pF}$	4.5 V	15	30	38	45	ns
		$C_L = 150\text{ pF}$	4.5 V	30	40	50	60	ns
t_{PHZ} , t_{PLZ}	Maximum Output Disable Time	$R_L = 1\text{ k}\Omega$	2.0 V	75	150	189	224	ns
		$C_L = 50\text{ pF}$	4.5 V	15	30	38	45	ns
		$C_L = 50\text{ pF}$	6.0 V	13	26	32	38	ns
		$C_L = 150\text{ pF}$	6.0 V	17	34	43	51	ns
t_{THL} , t_{TLH}	Maximum Output Rise and Fall Time	$C_L = 50\text{ pF}$	2.0 V	25	60	75	90	ns
		$C_L = 50\text{ pF}$	4.5 V	7	12	15	18	ns
		$C_L = 50\text{ pF}$	6.0 V	6	10	13	15	ns
C_{PD}	Power Dissipation Capacitance (Note 4)	$\bar{G} = V_{IH}$ $\bar{G} = V_{IL}$		10 50				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF
C_{OUT}	Maximum Output Capacitance			15	20	20	20	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

MM74HC540, MM74HC541

ORDERING INFORMATION

Device	Package	Shipping†
MM74HC540WM	SOIC-20 WB (Pb-Free and Halide Free)	38 Units / Tube
MM74HC540WMX		1000 / Tape & Reel
MM74HC540MTC	TSSOP-20 WB (Pb-Free)	75 Units / Tube
MM74HC540MTCX		2500 / Tape & Reel
MM74HC541WM	SOIC-20 WB (Pb-Free and Halide Free)	38 Units / Tube
MM74HC541WMX	SOIC-20, 300 mils (Pb-Free and Halide Free)	1000 / Tape & Reel
MM74HC541MTC	TSSOP-20 WB (Pb-Free)	75 Units / Tube
MM74HC541MTCX	TSSOP20, 4.4 × 6.5 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

MECHANICAL CASE OUTLINE

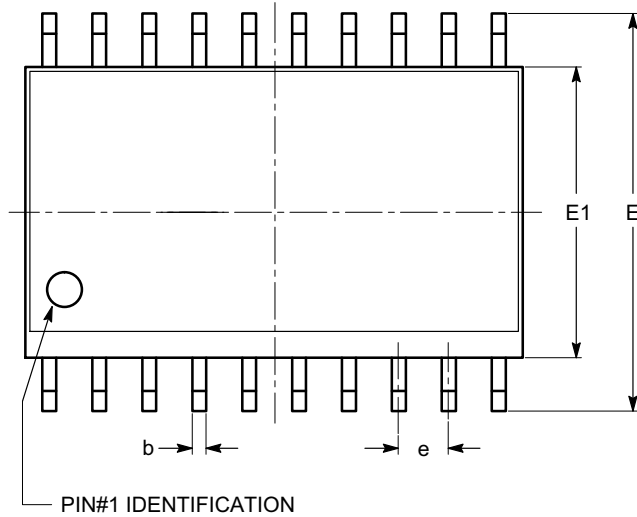
PACKAGE DIMENSIONS

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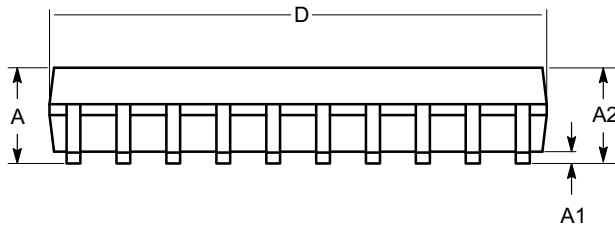
SOIC-20, 300 mils
CASE 751BJ-01
ISSUE O

DATE 19 DEC 2008

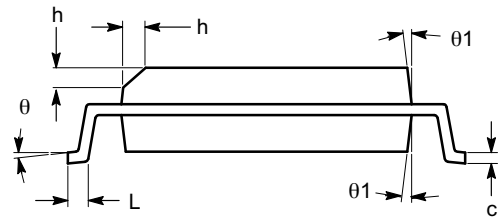


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	2.36	2.49	2.64
A1	0.10		0.30
A2	2.05		2.55
b	0.31	0.41	0.51
c	0.20	0.27	0.33
D	12.60	12.80	13.00
E	10.01	10.30	10.64
E1	7.40	7.50	7.60
e	1.27 BSC		
h	0.25		0.75
L	0.40	0.81	1.27
θ	0°		8°
$\theta 1$	5°		15°



SIDE VIEW



END VIEW

Notes:

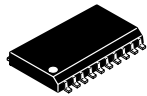
- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-013.

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DESCRIPTION:	SOIC-20, 300 MILS	PAGE 1 OF 1

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MECHANICAL CASE OUTLINE

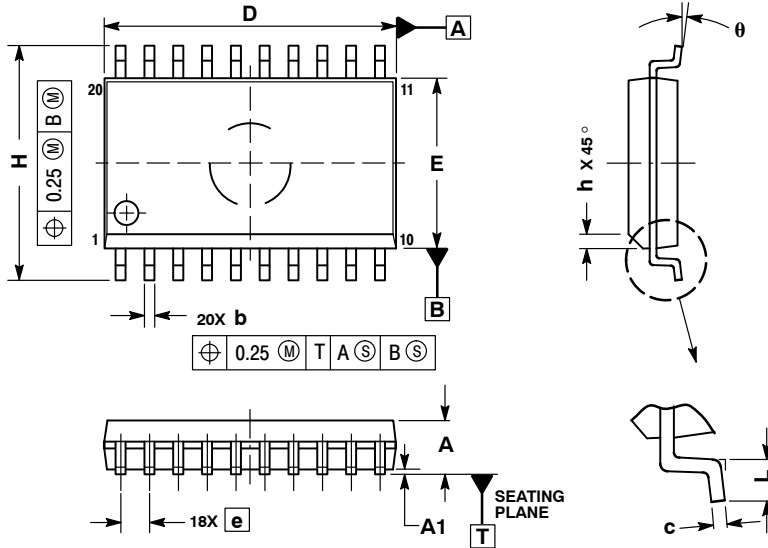
PACKAGE DIMENSIONS



SCALE 1:1

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015

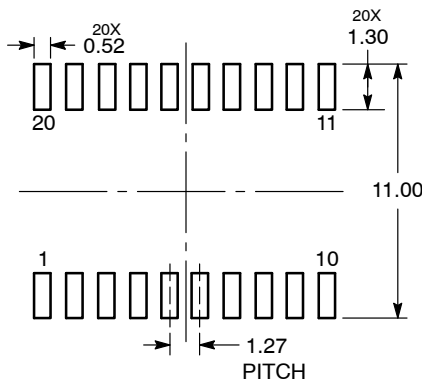


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

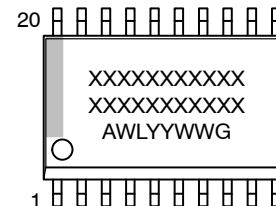
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	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

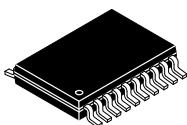
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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

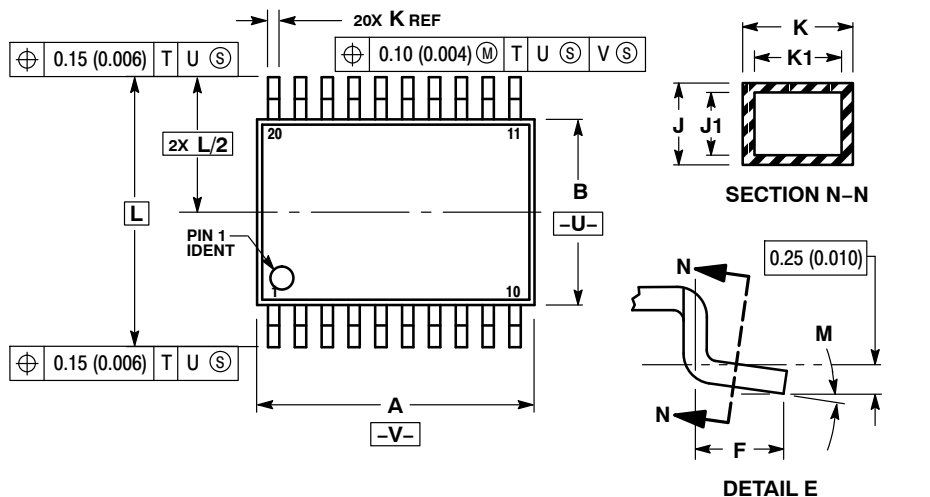
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TSSOP-20 WB
CASE 948E
ISSUE D

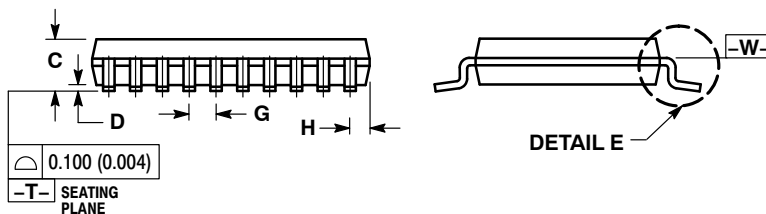
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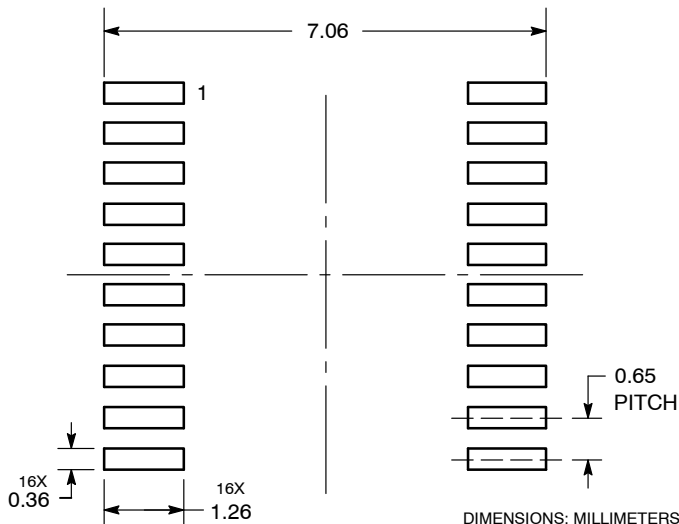


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

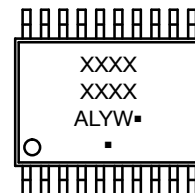
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	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°



SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM*



- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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MECHANICAL CASE OUTLINE

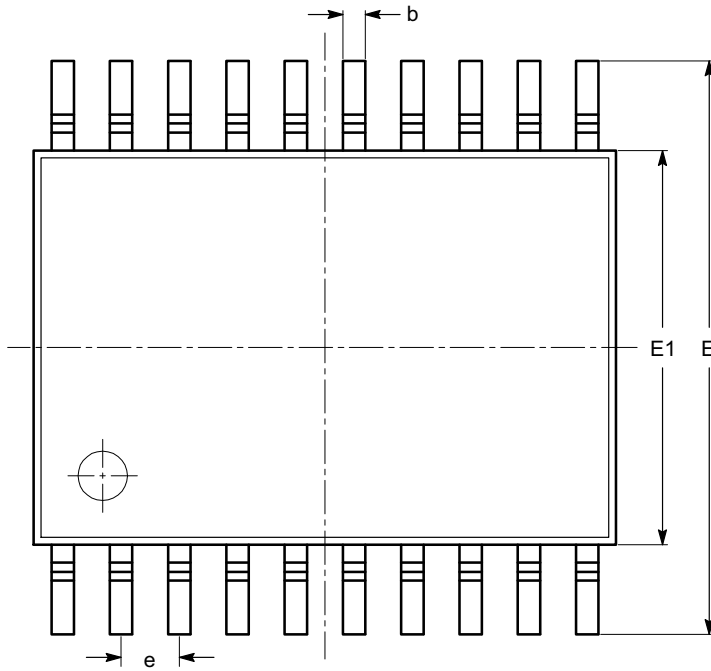
PACKAGE DIMENSIONS

ON Semiconductor®



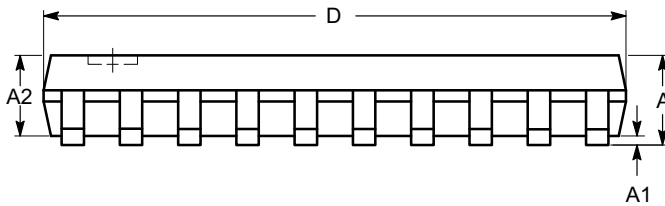
TSSOP20, 4.4x6.5
CASE 948AQ-01
ISSUE A

DATE 19 MAR 2009

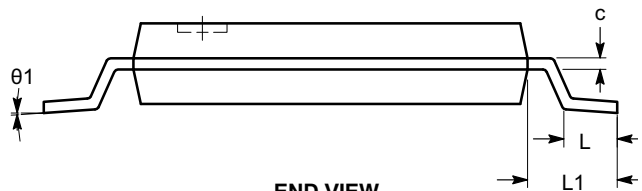


SYMBOL	MIN	NOM	MAX
A			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
c	0.09		0.20
D	6.40	6.50	6.60
E	6.30	6.40	6.50
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
θ	0°		8°

TOP VIEW



SIDE VIEW



END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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DESCRIPTION:	TSSOP20, 4.4X6.5	PAGE 1 OF 1

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